## NSN 5962-01-296-1085

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-296-1085

Body Length:	
0.960 inches	
Body Width:	
Between 0.220 inches and 0.310	) inches
Body Height:	
Between 0.140 inches and 0.18	5 inches
Maximum Power Dissipation F	lating:
950.0 milliwatts	
Operating Tempurature Range	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and burn in	and programmable and bipolar and schottky
Inclosure Material:	
Ceramic	
nclosure Configuration:	
Dual-in-line	
Output Logic Form:	
ransistor-transistor logic	
nput Circuit Pattern:	
12 input	
Case Outline Source And Des	gnator:
D-6 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per	Characteristic:
0.5 volts power source and 7.0	volts power source
Time Rating Per Chacteristic:	
125.00 nanoseconds propagation	on delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard (inc	udes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:	
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Moscuro	

Unit Of Measure:

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## NSN 5962-01-296-1085

Memory Microcircuit - Page 2 of 2

## Demilitarization:

Yes - demil/mli

Fiig:

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